

#### INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## IRF2204S

#### • FEATURES

- With TO-263( D2PAK ) packaging
- · High speed switching
- · Low gate input resistance
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

#### APPLICATIONS

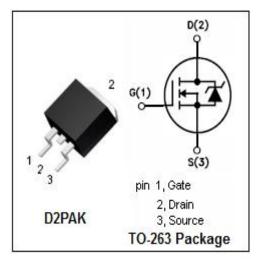
- · Power supply
- Switching applications

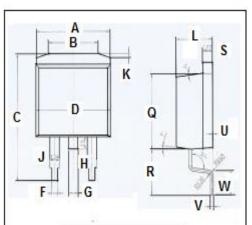
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	40	V				
V <sub>GSS</sub>	Gate-Source Voltage	±20	∧v				
lD	Drain Current-Continuous;Tc=25℃ Tc=100℃	170 120	A				
I <sub>DM</sub>	Drain Current-Single Pulsed	850	А				
P <sub>D</sub>	Total Dissipation	214	W				
Tj	Operating Junction Temperature	175	°C				
T <sub>stg</sub>	Storage Temperature	-55~175	°C				

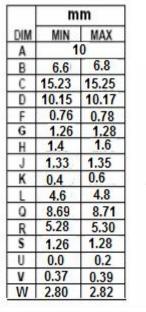
#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.75	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	

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#### isc website: www.iscsemi.cn

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### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	40			v
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.0		4.0	v
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =130A		3.0	3.6	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0V;Tc=25℃ V <sub>DS</sub> =32V; V <sub>GS</sub> = 0V; Tc=150℃			20 250	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =130A, V <sub>GS</sub> = 0 V		1.0	1.3	V

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